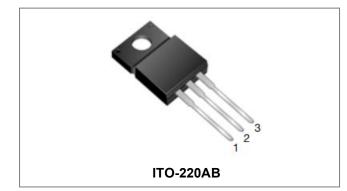
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# SDURF1530CT/CTR

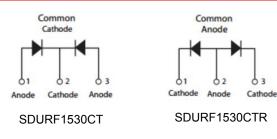
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SDURF1530CT/CTR ULTRAFAST RECTIFIER



### **Circuit Diagram**



### Applications

- Antiparallel diode for high frequency switching devices
- Anti saturation diode
- Snubber diode
- Free wheeling diode in converters and motor control circuits
- Rectifiers in switch mode power supplies (SMPS)
- Inductive heating and melting
- Uninterruptible power supplies (UPS)
- Ultrasonic cleaners and welders

### Features

- Ultra-Fast switching
- High current capability
- Low reverse leakage current
- High surge current capability
- This is a Pb free device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

### **Maximum Ratings:**

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V <sub>RRM</sub> V <sub>RWM</sub> V <sub>R</sub>	-	300	V
Average Rectified Forward Current	I <sub>F (AV)</sub>	50% duty cycle @Tc=105°C, rectangular wave form	8(Per Leg) 15(Per Device)	A
Peak One Cycle Non-Repetitive Surge Current(Per Leg)	I <sub>FSM</sub>	8.3ms, Half Sine pulse	80	А

### Electrical Characteristics:

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop(Per Leg)*	V <sub>F1</sub>	@8A, Pulse, T」= 25°C	1.01	1.3	V
	V <sub>F2</sub>	@8A, Pulse, T」= 150°C	-	1.2	V
Reverse Current(Per Leg)*	I <sub>R1</sub>	$@V_R = rated V_R$ , $T_J = 25^{\circ}C$	0.1	10	μA
	I <sub>R2</sub>	$@V_R = rated V_R$ , $T_J = 125^{\circ}C$	6	500	uA
Reverse Recovery Time(Per Leg)	trr	I⊧=500mA, I <sub>R</sub> =1A,and I <sub>m</sub> =250mA	30	45	ns

\* Pulse width < 300 µs, duty cycle < 2%

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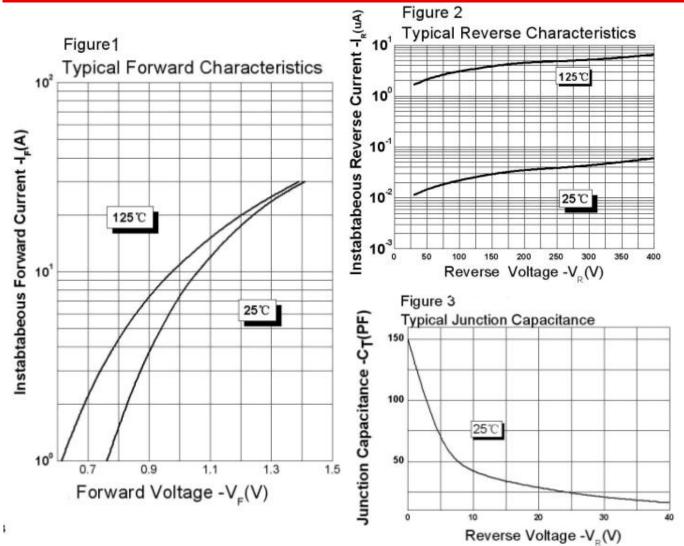
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RoHS 🗭

## Thermal-Mechanical Specifications:

Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	TJ	-	-55 to +150	°C
Storage Temperature	T <sub>stg</sub>	-	-55 to +150	°C
Typical Thermal Resistance Junction to Case	$R_{ ext{ heta}JC}$	DC operation	5	°C/W
Approximate Weight	wt	-	2	g
Case Style	ITO-220AB			







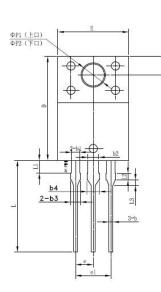
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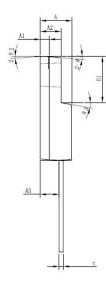
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### **Mechanical Dimensions ITO-220AB**

0





SYMBOL	Millimeters				
STMBOL	MIN.	TYP.	MAX.		
А	4.30	4.50	4.70		
A1	1.10	1.30	1.50		
A2	2.80	3.00	3.20		
A3	2.50	2.70	2.90		
b	0.50	0.60	0.75		
b1	1.10	1.20	1.35		
b2	1.50	1.60	1.75		
b3	1.20	1.30	1.45		
b4	1.60	1.70	1.85		
С	0.50	0.60	0.75		
D	14.80	15.00	15.20		
E	9.96	10.16	10.36		
е		2.55			
e1		5.10			
H1	6.50	6.70	6.90		
L	12.70	13.20	13.70		
L1	1.60	1.80	2.00		
L2	0.80	1.00	1.20		
L3	0.60	0.80	1.00		
<b>ΦΡ1(上口)</b>	3.30	3.50	3.70		
<b>ΦΡ2</b> (下口)	2.99	3.19	3.39		
Q	2.50	2.70	2.90		
Θ1		5°			
Θ2		4°			
Θ3		10°			
Θ4		5°			
Θ5		5°			

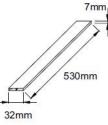
### **Ordering Information**

Device	Package	Shipping
SDURF1530CT(CTR)	ITO-220AB (Pb-Free)	50 pcs/ tube

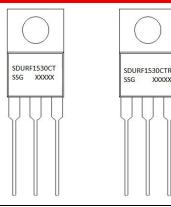
For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.



### **Tube Specification**



### **Marking Diagram**



Where XXXXX is YYWWL

```
SDUR
          = Device Type
          = Package type
= Forward Current (15A)
F
15
30
          = Reverse Voltage (300V)
CT(CTR)
         = Configuration
SSG
           = SSG
YΥ
           = Year
WW
           = Week
           = Lot Number
L
Cautions: Molding resin
            Epoxy resin UL:94V-0
```

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# SDURF1530CT/CTR



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